

HMC509LP5 / 509LP5E

v04.0811



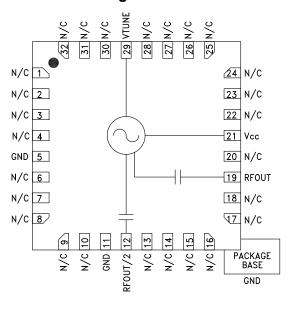
MMIC VCO w/ HALF FREQUENCY OUTPUT 7.8 - 8.8 GHz

Typical Applications

Low noise MMIC VCO w/Half Frequency, for:

- VSAT Radio
- Point to Point/Multi-Point Radio
- Test Equipment & Industrial Controls
- Military End-Use

Functional Diagram



Features

Dual Output: Fo = 7.8 - 8.8 GHz

Fo/2 = 3.9 - 4.4 GHz

Pout: +13 dBm

Phase Noise: -115 dBc/Hz @100 kHz Typ.

No External Resonator Needed

32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC509LP5 & HMC509LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC509LP5 & HMC509LP5E integrate resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +13 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

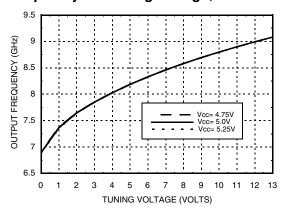
Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc = +5V

Parameter		Min.	Тур.	Max.	Units
Frequency Range	Fo Fo/2		7.8 - 8.8 3.9 - 4.4		GHz GHz
Power Output	RFOUT/2	+10 +5		+15 +10	dBm dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RFOUT			-115		dBc/Hz
Tune Voltage	Vtune	2		13	V
Supply Current (Icc) (Vcc = +5.0V)		200	250	270	mA
Tune Port Leakage Current (Vtune= 13V)				10	μA
Output Return Loss			2		dB
Harmonics/Subharmonics	1/2 2nd 3rd		35 10 32		dBc dBc dBc
Pulling (into a 2.0:1 VSWR)			5		MHz pp
Pushing @ Vtune= 5V			10		MHz/V
Frequency Drift Rate			0.9		MHz/°C

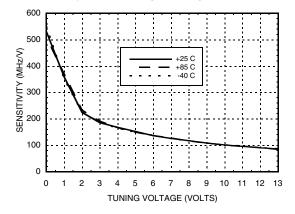




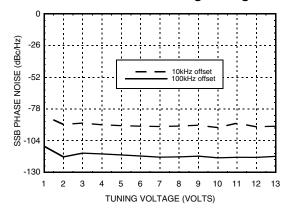
Frequency vs. Tuning Voltage, T= 25°C



Sensitivity vs. Tuning Voltage, Vcc= +5V

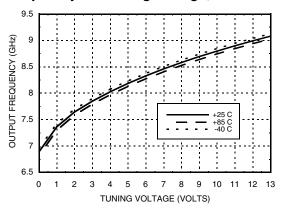


SSB Phase Noise vs. Tuning Voltage

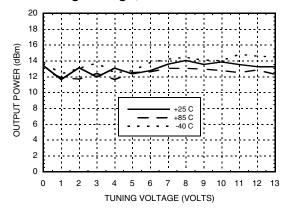


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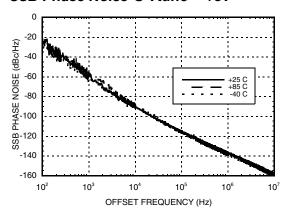
Frequency vs. Tuning Voltage, Vcc= +5V



Output Power vs. Tuning Voltage, Vcc= +5V



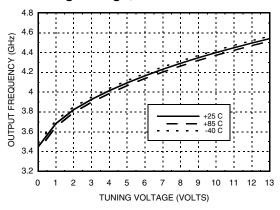
SSB Phase Noise @ Vtune = +5V





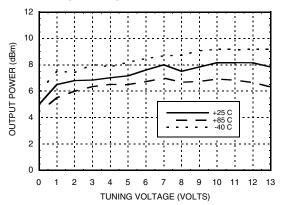


RFOUT/2 Frequency vs. Tuning Voltage, Vcc= +5V



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RFOUT/2 Output Power vs. Tuning Voltage, Vcc= +5V



Absolute Maximum Ratings

Vcc	+5.5 Vdc	
Vtune	0 to +15V	
Junction Temperature	135 °C	
Continuous Pdiss (T=85 °C) (derate 26.7 mW/C above 85 °C	1.34 W	
Thermal Resistance (junction to ground paddle)	37.3 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD Sensitivity (HBM)	Class 1A	

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)	
4.75	210	
5.0	250	
5.25	270	

Note: VCO will operate over full voltage range shown above.



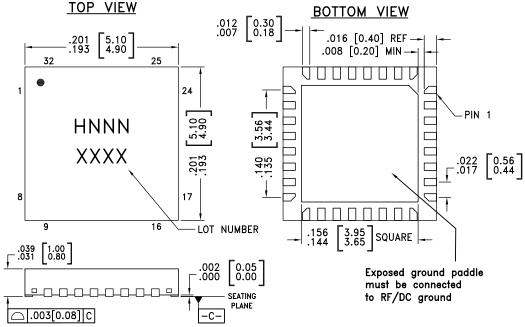
ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS





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Outline Drawing



NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC509LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 [1]	H509 XXXX
HMC509LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[2]	<u>H509</u> XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX





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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 4, 6 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
12	RFOUT/2	Half frequency output (AC coupled).	HORFOUT/2
19	RFOUT	RF output (AC coupled).	RFOUT
21	Vcc	Supply Voltage, +5V	VccO 14pF
29	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNE 0 3nH 4pF 75pF
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	○ GND =